

# BC447G

#### **BC447G Information**



Part Number	BC447G	
Manufacturer	ON Semiconductor	
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single	
Description	TRANS NPN 80V 0.3A TO-92	
Package	TO-226-3, TO-92-3 (TO-226AA)	
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com	



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## **Certified Quality**

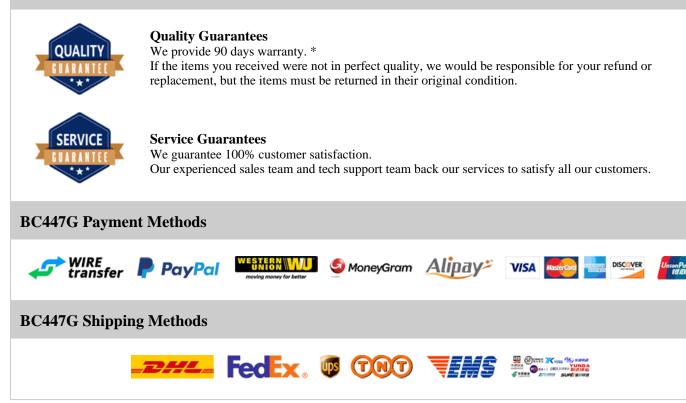
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



### **BC447G Specifications**

Manufacturer Part NumberBC447GManufacturerON SemiconductorCategoryDiscrete Semiconductor ProductsCategoryTransistor ProductsPackageTo-226-3, TO-92-3 (TO-226AA)Series-Transistor TypeNPNCurrent - Collector (Ic) (Max)300mAVoltage - Collector Emitter Breakdown (Max)80VVcc Saturation (Max) @ Ib, Ic250mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce50 @ 2mA, 5VPower - Max625mWPrequency - Transition200MHzOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeThrough Hole		
CategoryDiscrete Semiconductor ProductsTransistors - Bipolar (BJT) - SinglePackageTO-226-3, TO-92-3 (TO-226AA)Series-Transistor TypeNPNCurrent - Collector (Ic) (Max)300mAVoltage - Collector Emitter Breakdown (Max)80VVcc Saturation (Max) @ Ib, Ic250mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce50 @ 2mA, 5VPower - Max625mWFrequency - Transition200MHzOperating Temperature-55°C ~ 150°C (TJ)	Manufacturer Part Number	
Frequency - TransitionTransistors - Bipolar (BJT) - SinglePackageTO-226-3, TO-92-3 (TO-226AA)Series-Transistor TypeNPNCurrent - Collector (Lc) (Max)300mAVoltage - Collector Emitter Breakdown (Max)80VVce Saturation (Max) @ Ib, Ic250mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce50 @ 2mA, 5VPower - Max625mWFrequency - Transition200MHzOperating Temperature-55°C ~ 150°C (TJ)	Manufacturer	
PackageTO-226-3, TO-92-3 (TO-226AA)Series-Transistor TypeNPNCurrent - Collector (Lo) (Max)300mAVoltage - Collector Emitter Breakdown (Max)80VVcc Saturation (Max) @ Ib, Ic250mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce50 @ 2mA, 5VPower - Max625mWFrequency - Transition200MHzOperating Temperature-55°C ~ 150°C (TJ)	Category	
Series-Transistor TypeNPNCurrent - Collector (Ic) (Max)300mAVoltage - Collector Emitter Breakdown (Max)80VVce Saturation (Max) @ Ib, Ic250mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce50 @ 2mA, 5VPower - Max625mWFrequency - Transition200MHzOperating Temperature-55°C ~ 150°C (TJ)		e
Transistor TypeNPNCurrent - Collector (Lc) (Max)300mAVoltage - Collector Emitter Breakdown (Max)80VVce Saturation (Max) @ Ib, Ic250mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce50 @ 2mA, 5VPower - Max625mWFrequency - Transition200MHzOperating Temperature-55°C ~ 150°C (TJ)	Package	
Current - Collector (Lc) (Max)300mAVoltage - Collector Emitter Breakdown (Max)80VVce Saturation (Max) @ Ib, Ic250mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce50 @ 2mA, 5VPower - Max625mWFrequency - Transition200MHzOperating Temperature-55°C ~ 150°C (TJ)	Series	
Voltage - Collector Emitter Breakdown (Max)80VVce Saturation (Max) @ Ib, Ic250mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce50 @ 2mA, 5VPower - Max625mWFrequency - Transition200MHzOperating Temperature-55°C ~ 150°C (TJ)	Transistor Type	
Vce Saturation (Max) @ Ib, Ic   250mV @ 10mA, 100mA     Current - Collector Cutoff (Max)   100nA (ICBO)     DC Current Gain (hFE) (Min) @ Ic, Vce   50 @ 2mA, 5V     Power - Max   625mW     Frequency - Transition   200MHz     Operating Temperature   -55°C ~ 150°C (TJ)	Current - Collector (Ic) (Max)	
Current - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce50 @ 2mA, 5VPower - Max625mWFrequency - Transition200MHzOperating Temperature-55°C ~ 150°C (TJ)	Voltage - Collector Emitter Breakdown (Max)	
DC Current Gain (hFE) (Min) @ Ic, Vce 50 @ 2mA, 5V   Power - Max 625mW   Frequency - Transition 200MHz   Operating Temperature -55°C ~ 150°C (TJ)	Vce Saturation (Max) @ Ib, Ic	
Power - Max625mWFrequency - Transition200MHzOperating Temperature-55°C ~ 150°C (TJ)	Current - Collector Cutoff (Max)	
Frequency - Transition200MHzOperating Temperature-55°C ~ 150°C (TJ)	DC Current Gain (hFE) (Min) @ Ic, Vce	
Operating Temperature $-55^{\circ}\text{C} \sim 150^{\circ}\text{C} \text{(TJ)}$	Power - Max	
	Frequency - Transition	
Mounting Type Through Hole	Operating Temperature	
	Mounting Type	
Package / Case TO-226-3, TO-92-3 (TO-226AA)	Package / Case	
Supplier Device Package TO-92-3	Supplier Device Package	
Report e		Report errors?

#### **BC447G Guarantees**



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